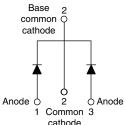


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### Schottky Rectifier, 2 x 7.5 A



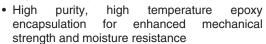


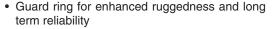
Base 2 common C cathode	
Anode O 2	Anode
	imon 3 iode

PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 7.5 A				
$V_R$	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.57 V				
I <sub>RM</sub> max.	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	7 mJ				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation







- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### **DESCRIPTION**

The VS-MBR15...CT... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform	15	А						
V <sub>RRM</sub>		35/45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	690	А						
V <sub>F</sub>	7.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	- 65 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR1535CTPbF	VS-MBR1535CT-N3	VS-MBR1545CTPbF	VS-MBR1545CT-N3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	35	33	45	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg		T = 121 °C rotod V	T 404.00 mindly				
forward current	per device	I <sub>F(AV)</sub>	$T_C = 131$ °C, rated $V_R$		15			
Maximum peak one cycle non-repetitive surge		I <sub>FSM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse Following any rated load condition and with rated $V_{RRM}$ applied		690	А		
		1 0141	Surge applied at rated load condition half wave single phase 60 Hz		150			
Non-repetitive avalanche energ	y per leg	E <sub>AS</sub>	$T_{J} = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 3.5  \text{mH}$		7	mJ		
Repetitive avalanche current pe	r leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		2	Α		



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T <sub>J</sub> = 25 °C	0.84			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	7.5 A	T <sub>.1</sub> = 125 °C	0.57	V		
		15 A	1J = 125 C	0.72			
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	- mA		
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	15			
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		400	pF		
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub>				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperate	ure range	TJ		- 65 to 150	°C	
Maximum storage temperatu	ire range	T <sub>Stg</sub>		- 65 to 175	°C	
Maximum thermal resistance junction to case per leg	<del>)</del> ,	R <sub>thJC</sub>	DC operation	3.0		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>	DC operation	60		
Anarovimoto weight				2	g	
Approximate weight				0.07	OZ.	
minimum				6 (5)	kgf · cm	
Mounting torque	maximum	1		12 (10)	(lbf · in)	
Marking device			Casa style TO 220AB	MBR1	535CT	
			Case style TO-220AB	MBR1	MBR1545CT	

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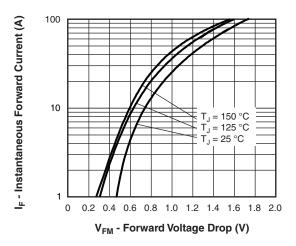


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

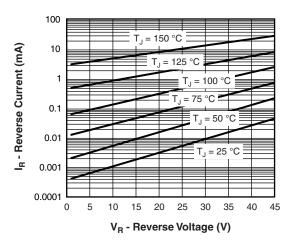


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

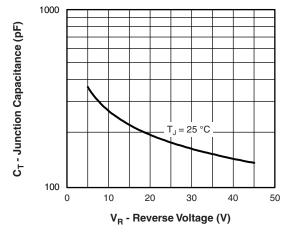


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

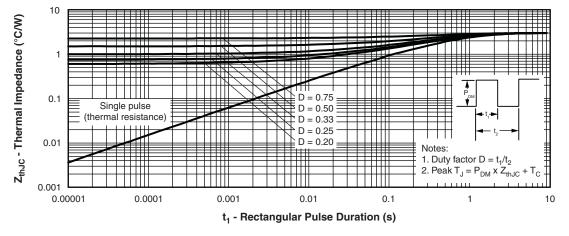


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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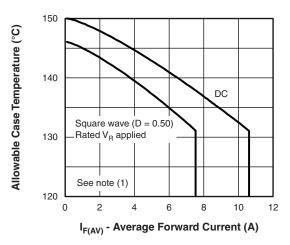


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

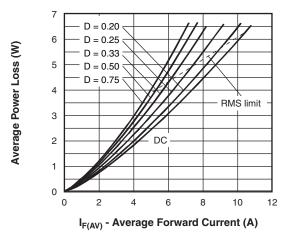


Fig. 6 - Forward Power Loss Characteristics

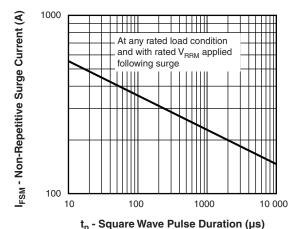


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

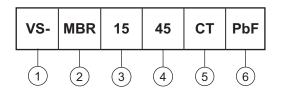
#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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#### **ORDERING INFORMATION TABLE**





Vishay Semiconductors product

2 - Schottky MBR series

- Current rating (15 = 15 A)

35 = 35 V 45 = 45 V

Voltage ratingsCT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBR1535CTPbF	50	1000	Antistatic plastic tube					
VS-MBR1535CT-N3	50	1000	Antistatic plastic tube					
VS-MBR1545CTPbF	50	1000	Antistatic plastic tube					
VS-MBR1545CT-N3	50	1000	Antistatic plastic tube					

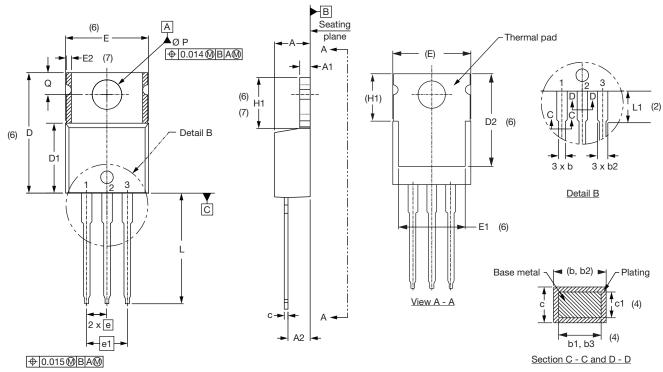
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dest seed in a information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95294			



### Vishay Semiconductors

### **TO-220AB**

#### **DIMENSIONS** in millimeters and inches



#### <u>Lead assignments</u> <u>Diodes</u>



- 1. Anode/open
- 2. Cathode
- 3. Anode

#### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØP	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- 6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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